

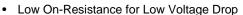
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P-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}$ (Ω) Max.	I _D (A)	Q _g (Typ.)			
- 30	0.016 at V _{GS} = - 10 V	- 50 ^d	43.1 nC			
	0.022 at $V_{GS} = -4.5 \text{ V}$	- 50 ^d	43.1110			

FEATURES

DT-Trench Power MOSFET

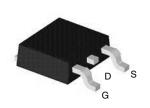


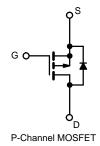
Extended V_{GS} max. Rating: 25 V

100 % R_q and UIS Tested



TO-252 Pin Configuration





APPLICATIONS

- · Battery, Load and Adaptor Switches
 - Notebook Computers
 - Notebook Battery Packs

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless oth	erwise noted)	
Parameter	Symbol	
	17	

Parameter			Limit	Unit	
Drain-Source Voltage	V _{DS}	- 30	V		
Gate-Source Voltage			± 25	V	
	T _C = 25 °C		- 50 ^d		
Continuous Drain Current (T _{.1} = 150 °C)	T _C = 70 °C		- 50 ^d		
Continuous Diain Curient (1) = 130 C)	T _A = 25 °C	l _D	- 23.1 ^{a, b}		
	T _A = 70 °C	1	- 18.4 ^{a, b}		
Pulsed Drain Current (t = 100 μs)		I _{DM}	- 300	Α	
Continuous Source-Drain Diode Current	T _C = 25 °C	I _S	- 50 ^d		
Continuous Source-Diain blode Current	T _A = 25 °C		- 4.1 ^{a, b}		
Avalanche Current L = 0.1 mH		I _{AS}	- 25		
Single-Pulse Avalanche Energy			31.2	mJ	
	T _C = 25 °C		48	1	
Maximum Power Dissipation	T _C = 70 °C	P_{D}	31	W	
Maximum Fower Dissipation	T _A = 25 °C	1 'D	5 ^{a, b}		
	T _A = 70 °C	1	3.2 ^{a, b}		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 150	°C		
Soldering Recommendations (Peak Temperature) ^{e, f}		260			

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^{a, c}	t ≤ 10 s	R _{thJA}	21	25	°C/W	
Maximum Junction-to-Case	Steady State	R _{thJC}	2.1	2.6	C/VV	

Notes:

- a. Surface mounted on 1" x 1" FR4 board.
- b. t = 10 s.
- c. Maximum under steady state conditions is 70 °C/W.
- e. The TO-252 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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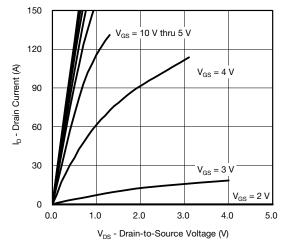
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	1	<u>'</u>					
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0, I_D = -250 \mu A$	- 30			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$			- 22		. 1//02	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$ $I_D = -250 \mu A$			4.1		mV/°C	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	- 1.2		- 2.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 25 \text{ V}$			± 100	nA	
-		V _{DS} = - 30 V, V _{GS} = 0 V			- 1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 30 V, V _{GS} = 0 V, T _J = 55 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	V _{DS} ≥ - 10 V, V _{GS} = - 10 V	- 30			Α	
	_ (=::,	V _{GS} = - 10 V, I _D = - 15 A		0.012	0.016	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 10 A		0.018	0.022		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 15 A		60		S	
Dynamic ^b	0.0						
Input Capacitance	C _{iss}			5125			
Output Capacitance	C _{oss}	V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz		615		pF	
Reverse Transfer Capacitance	C _{rss}			554		٠,	
·		V _{DS} = - 15 V, V _{GS} = - 10 V, I _D = - 10 A		90	135	+	
Total Gate Charge	Q _g	B3 + 7 G3 + 7 B		43.1	65	nC	
Gate-Source Charge		$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -10 \text{ A}$		13.6			
Gate-Drain Charge	Q _{gd}			28.8			
Gate Resistance	R _g	f = 1 MHz	0.5	2.4	4.8	Ω	
Turn-On Delay Time	t _{d(on)}			15	30		
Rise Time	t _r	$V_{DD} = -15 \text{ V, R}_{1} = 1.5 \Omega$		12	24		
Turn-Off DelayTime	t _{d(off)}	$I_D \cong -10 \text{ A}, V_{GEN} = -10 \text{ V}, R_q = 1 \Omega$		58	110		
Fall Time	t _f			12	24	1	
Turn-On Delay Time	t _{d(on)}			60	120	ns	
Rise Time	t _r	$V_{DD} = -15 \text{ V, R}_{1} = 1.5 \Omega$		60	120		
Turn-Off DelayTime	t _{d(off)}	$I_D \cong -10 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_q = 1 \Omega$		52	100		
Fall Time	t _f	-		26	52	1	
Drain-Source Body Diode Characteris					l	<u> </u>	
Continous Source-Drain Diode Current	I _S	T _C = 25 °C			- 50		
Pulse Diode Forward Current (100 μs)	I _{SM}	-			- 300	A	
Body Diode Voltage	V _{SD}	I _S = -3 A, V _{GS} = 0		- 0.74	- 1.20	V	
Body Diode Reverse Recovery Time	t _{rr}			23	46	ns	
Body Diode Reverse Recovery Charge	Diode Reverse Recovery Charge Q _{rr}			12	24	nC	
Reverse Recovery Fall Time	t _a	1 i _F = - 10 A, αί/αι = 100 Αγμ5, 1 j = 25 °C		9		ns	
Reverse Recovery Rise Time	t _b	t _b		14		7 115	

Notes

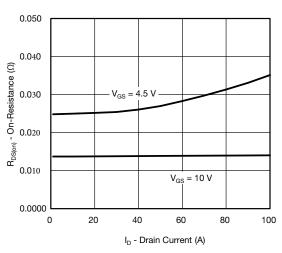
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

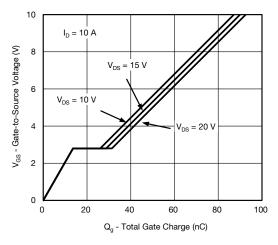




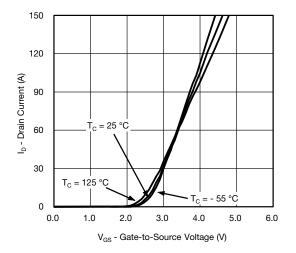
Output Characteristics



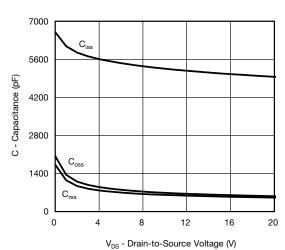
On-Resistance vs. Drain Current



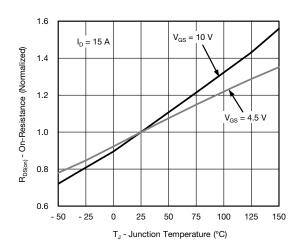
Gate Charge



Transfer Characteristics

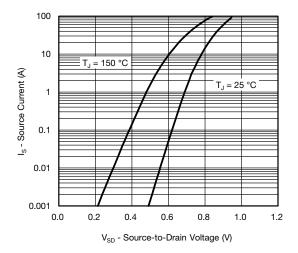


Capacitance

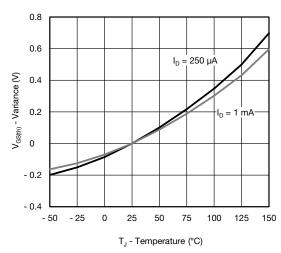


On-Resistance vs. Junction Temperature

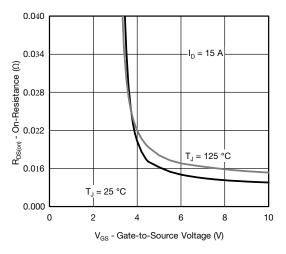




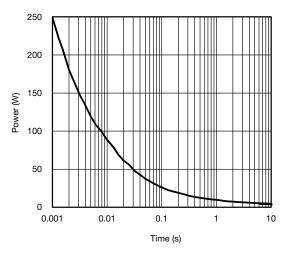
Source-Drain Diode Forward Voltage



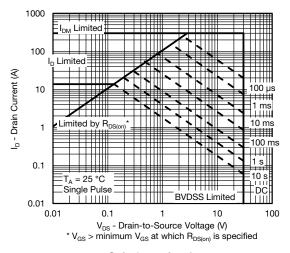
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage

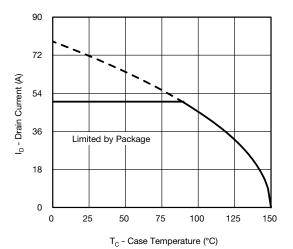


Single Pulse Power, Junction-to-Ambient

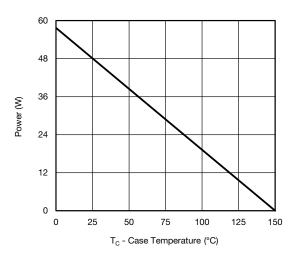


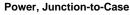
Safe Operating Area

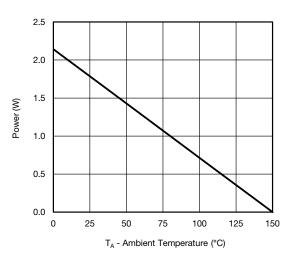




Current Derating*



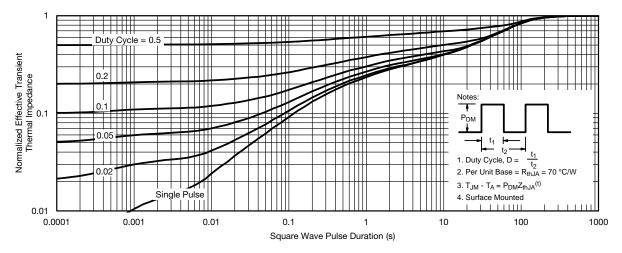




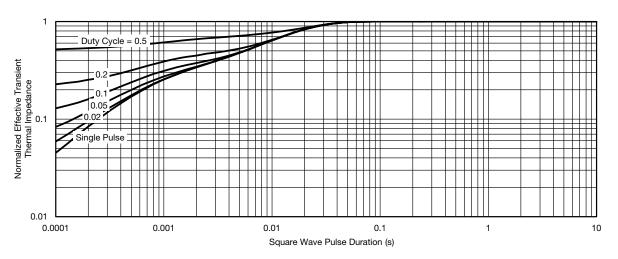
Power Derating, Junction-to-Ambient

^{*} The power dissipation P_D is based on $T_{J(max.)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.





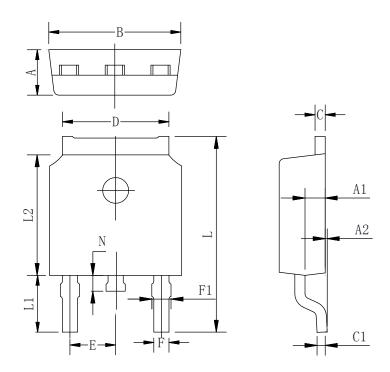
Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case



TO-252-2L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Symbol	Min	Тур	Max	
A	2.10	2.30	2.50	
A1	0.88	1.01	1.16	
A2	0.00	0.15	0.28	
В	6.40	6.60	6.80	
С	0.42	0.50	0.63	
C1	0.42	0.50	0.63	
D	5.08	5.32	5.65	
Е	2.286 TYP			
F	0.63	0.76	0.89	
F1	0.64	0.86	1.08	
L	9.30	9.90	10.80	
L1	2.4	2.8	3.6	
L2	5.90	6.10	6.55	
N	0.57	0.80	1.05	





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